# Description

The 9ZXL1251 meets the demanding requirements of the Intel DB1200ZL specification, including the critical low-drift requirements of Intel CPUs. It is pin compatible to the 9ZXL1231 and integrates 24 termination resistors, saving 41mm<sup>2</sup> board area.

# Applications

Buffer for Romley, Grantley and Purley Servers, solid state storage and PCIe

# **Output Features**

 12 LP-HCSL Output Pairs w/integrated terminations (Zo = 85Ω)

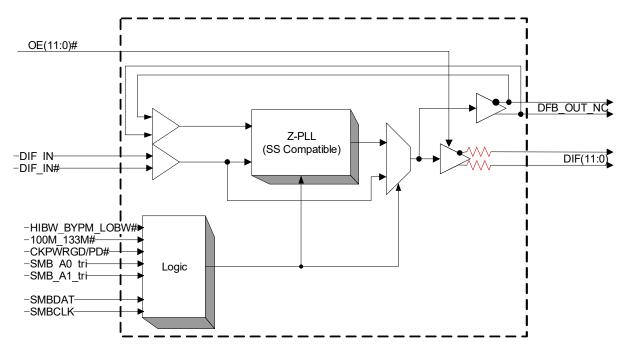
# **Key Specifications**

- Cycle-to-cycle jitter < 50ps
- Output-to-output skew < 50ps</li>
- Input-to-output delay variation < 50ps</li>
- PCIe Gen3 phase jitter < 1.0ps RMS</li>
- Phase jitter: QPI/UPI > = 9.6GB/s < 0.2ps rms

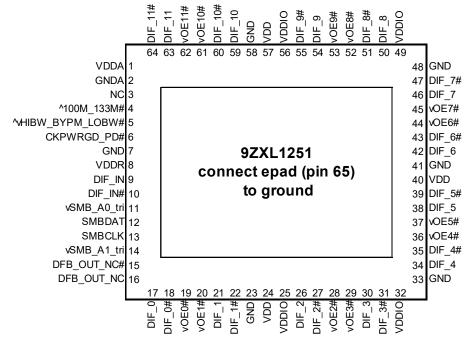
# **Block Diagram**

## Features

- 25MHz PFT clock delay management
- $85\Omega$  Low-power push-pull HCSL outputs; eliminate 24 resistors, save  $41mm^2$  of area
- Pin compatible to 9ZX21201 and 9ZXL1231; easy path to power and area savings
- Space-saving 64-pin VFQFPN package
- · Fixed feedback path for 0ps input-to-output delay
- 9 selectable SMBus addresses; multiple devices can share the same SMBus segment
- 12 OE# pins; hardware control of each output
- PLL or bypass mode; supports common and separate clock architectures
- Selectable PLL bandwidth; minimizes jitter peaking in downstream PLLs
- Spread spectrum compatible; tracks spreading input clock for low EMI
- -40°C to +85°C device available; supports demanding environmental applications



## **Pin Configuration**



#### 9 x 9mm VFQFPN package

Note: Pins with ^ prefix have internal 120K pullup Pins with v prefix have internal 120K pulldowm Pins with ^v prefix have internal 120K pullup/pulldown (biased to VDD/2)

### **Power Management Table**

CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	DIF(11:0)/ DIF(11:0)#	PLL STATE IF NOT IN BYPASS MODE
0	Х	Х	Low/Low	OFF
1	Bunning	0	Low/Low	ON
	Running	1	Running	ON

### Functionality at Power-up (PLL mode)

100M_133M#	DIF_IN MHz	DIF(11:0)
1	100.00	DIF_IN
0	133.33	DIF_IN

### **Power Connections**

	Pin Number		
VDD	VDDIO	GND	Description
1		2	Analog PLL
8		7	Analog Input
24,40,57	25,32,49,56	23,33,41,48, 58,65	DIF clocks

### PLL Operating Mode Readback Table

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6
Low (Low BW)	0	0
Mid (Bypass)	0	1
High (High BW)	1	1

### PLL Operating Mode

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

### 9ZXL1251 SMBus Addressing

P	Pin	
SMB_A1_tri	SMB_A0_tri	SMBus Address
0	0	D8
0	М	DA
0	1	DE
М	0	C2
М	М	C4
М	1	C6
1	0	CA
1	М	CC
1	1	CE

# **Pin Descriptions**

PIN #	PIN NAME	TYPE	DESCRIPTION
1	VDDA	PWR	Power for the PLL core.
2	GNDA	GND	Ground pin for the PLL core.
3	NC	N/A	No Connection.
4	^100M_133M#	IN	3.3V Input to select operating frequency. This pin has an internal pull-up resistor. See Functionality Table for Definition
-		LATCHED	Trilevel input to select High BW, Bypass or Low BW mode. This pin is biased to VDD/2
5	^vHIBW_BYPM_LOBW#	IN	(Bypass mode) with internal pull up/pull down resistors. See PLL Operating Mode Table for
6	CKPWRGD_PD#	IN	3.3V Input notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on subsequent assertions. Low enters Power Down Mode.
7	GND	GND	Ground pin.
8	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
9	DIF IN	IN	HCSL True input
-	DIF IN#	IN	HCSL Complementary Input
	vSMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9 SMBus Addresses. It has an internal 120Kohm pull down resistor.
12	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
-	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
	vSMB_A1_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9 SMBus Addresses. It has an internal 120Kohm pull down resistor.
15	DFB_OUT_NC#	OUT	Complementary half of differential feedback output, provides feedback signal to the PLL for synchronization with input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
16	DFB_OUT_NC	OUT	True half of differential feedback output, provides feedback signal to the PLL for synchronization with the input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
17	DIF_0	OUT	HCSL true clock output
18	DIF_0#	OUT	HCSL Complementary clock output
19	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
20	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
21	DIF 1	OUT	HCSL true clock output
22	 DIF_1#	OUT	HCSL Complementary clock output
23	GND	GND	Ground pin.
24	VDD	PWR	Power supply, nominal 3.3V
25	VDDIO	PWR	Power supply for differential outputs
26	DIF_2	OUT	HCSL true clock output
27	DIF_2#	OUT	HCSL Complementary clock output
28	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
29	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
30	DIF 3	OUT	HCSL true clock output
31	DIF 3#	OUT	HCSL Complementary clock output
	VDDIO	PWR	Power supply for differential outputs
	GND	GND	Ground pin.
	DIF 4	OUT	HCSL true clock output
	DIF_4#	OUT	HCSL Complementary clock output
	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs

# Pin Descriptions (cont.)

	PIN NAME	TYPE	DESCRIPTION
38 I	DIF_5	OUT	HCSL true clock output
39 I	DIF_5#	OUT	HCSL Complementary clock output
40	VDD	PWR	Power supply, nominal 3.3V
41 (	GND	GND	Ground pin.
42 I	DIF_6	OUT	HCSL true clock output
43 I	DIF_6#	OUT	HCSL Complementary clock output
44	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.
44	VUE0#	IIN	1 =disable outputs, 0 = enable outputs
45	VOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.
45 v	vOE7#	IIN	1 =disable outputs, 0 = enable outputs
46 I	DIF_7	OUT	HCSL true clock output
47 1	DIF_7#	OUT	HCSL Complementary clock output
48 (	GND	GND	Ground pin.
49	VDDIO	PWR	Power supply for differential outputs
50 I	DIF 8	OUT	HCSL true clock output
51 I	DIF_8#	OUT	HCSL Complementary clock output
50		INI	Active low input for enabling DIF pair 8. This pin has an internal pull-down.
52 v	vOE8#	IN	1 =disable outputs, 0 = enable outputs
50		INI	Active low input for enabling DIF pair 9. This pin has an internal pull-down.
53 v	vOE9#	IN	1 =disable outputs, 0 = enable outputs
54 I	DIF_9	OUT	HCSL true clock output
55 I	DIF_9#	OUT	HCSL Complementary clock output
56	VDDIO	PWR	Power supply for differential outputs
57	VDD	PWR	Power supply, nominal 3.3V
58 0	GND	GND	Ground pin.
59 I	DIF_10	OUT	HCSL true clock output
60 I	DIF_10#	OUT	HCSL Complementary clock output
C1 .	OF40#	INI	Active low input for enabling DIF pair 10. This pin has an internal pull-down.
61 v	vOE10#	IN	1 =disable outputs, 0 = enable outputs
60	VOE11#	INI	Active low input for enabling DIF pair 11. This pin has an internal pull-down.
62 \	vOE11#	IN	1 =disable outputs, 0 = enable outputs
63 I	DIF_11	OUT	HCSL true clock output
	 DIF_11#	OUT	HCSL Complementary clock output
	epad	GND	epad, connect to ground

# **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the 9ZXL1251. These ratings, which are standard values for Renesas commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx				4.6	V	1,2
Input Low Voltage	V <sub>IL</sub>		GND-0.5			V	1
Input High Voltage	V <sub>IH</sub>	Except for SMBus interface			V <sub>DD</sub> +0.5	V	1,3
Input High Voltage	VIHSMB	SMBus clock and data pins			5.5	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>3</sup> Not to exceed 4.6V.

## **Electrical Characteristics–DIF\_IN Clock Input Parameters**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V <sub>CROSS</sub>	Crossover Voltage	150		900	mV	1
Input Swing - DIF_IN	V <sub>SWING</sub>	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{DD}$ , $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d <sub>tin</sub>	Measurement from differential waveform	45		55	%	1
Input Jitter - Cycle to Cycle	J <sub>DIFIn</sub>	Differential Measurement	0		125	ps	1

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Slew rate measured through +/-75mV window centered around differential zero.

# **Electrical Characteristics-SMBus**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

				-			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
SMBus Input Low Voltage	VILSMB				0.8	V	
SMBus Input High Voltage	VIHSMB		2.1		V <sub>DDSMB</sub>	V	
SMBus Output Low Voltage	V <sub>OLSMB</sub>	At I <sub>PULLUP</sub>			0.4	V	
SMBus Sink Current	I <sub>PULLUP</sub>	At V <sub>OL</sub>	4			mA	
Nominal Bus Voltage	V <sub>DDSMB</sub>		2.7		3.6	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	5

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Control input must be monotonic from 20% to 80% of input swing.

<sup>3</sup> Time from deassertion until outputs are > 200mV.

<sup>4</sup> DIF\_IN input.

<sup>5</sup> The differential input clock must be running for the SMBus to be active.

## **Electrical Characteristics–Input/Supply/Common Parameters**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX		NOTES
Supply Voltage	VDDx	Supply voltage, except VDDIO	3.135	3.3	3.465	V	
Output Supply Voltage	VDDIO	Supply voltage for DIF outputs, if present	0.95	1.05	3.465		
Ambient Operating	T <sub>AMB</sub>	Commercial range (T <sub>COM</sub> )	0		70	-	
Temperature	' AMB	Industrial range (T <sub>IND</sub> )	-40		85	°C	
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus, tri-level inputs	2		V <sub>DD</sub> + 0.3	V	
Input Low Voltage	V <sub>IL</sub>	Single-ended inputs, except SMBus, tri-level inputs	GND - 0.3		0.8	V	
Input High Voltage	V <sub>IHTRI</sub>	Tri-Level Inputs	2.2		V <sub>DD</sub> + 0.3	V	
Input Mid Voltage	V <sub>IMTRI</sub>	Tri-Level Inputs	1.2	VDD/2	1.8	V	
Input Low Voltage	V <sub>ILTRI</sub>	Tri-Level Inputs	GND - 0.3		0.8	V	
	I <sub>IN</sub>	Single-ended inputs, $V_{IN}$ = GND, $V_{IN}$ = VDD	-5		5	uA	
		Single-ended inputs					
Input Current	I <sub>INP</sub>	$V_{IN} = 0 V$ ; Inputs with internal pull-up resistors	-200		200	uA	
		V <sub>IN</sub> = VDD; Inputs with internal pull-down resistors				3.465       V         70       °C         85       °C         p+0.3       V         0.8       V         0.8       V         200       uA         150       MHz         110       MHz         147       MHz         7       nH         5       pF         2.7       pF         6       pF         1.8       ms         33       kHz         10       clocks         300       us	
	F <sub>ibyp</sub>	V <sub>DD</sub> = 3.3 V, Bypass mode	25		150	MHz	
Input Frequency	F <sub>ipll</sub>	V <sub>DD</sub> = 3.3 V, 100MHz PLL mode	25	100.00	110	MHz	
	F <sub>ipll</sub>	V <sub>DD</sub> = 3.3 V, 133.33MHz PLL mode	120	133.33	147	MHz	
Pin Inductance	L <sub>pin</sub>				7	nH	1
	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C <sub>INDIF_IN</sub>	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	- -	From V <sub>DD</sub> Power-Up and after input clock		0.18	1.0		10
CIK Stabilization	T <sub>STAB</sub>	stabilization or de-assertion of PD# to 1st clock		0.10	1.0	ms	1,2
Input SS Modulation	f <sub>MODINPCIe</sub>	Allowable Frequency for PCle Applications	30		33	kHz	
Frequency PCle	MODINPCIE	(Triangular Modulation)					
OE# Latency	t <sub>LATOE</sub> #	DIF start after OE# assertion DIF stop after OE# deassertion	4		10	clocks	1,2,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t <sub>F</sub>	Fall time of control inputs			5	ns	2
Trise	t <sub>R</sub>	Rise time of control inputs			5	ns	2

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Control input must be monotonic from 20% to 80% of input swing.

<sup>3</sup> Time from deassertion until outputs are > 200mV.

<sup>4</sup> DIF\_IN input.

# **Electrical Characteristics–DIF Low Power HCSL Outputs**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

					0		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	te dV/dt	T <sub>AMB</sub> = T <sub>COM</sub> , Scope averaging on	1.6	3.3	4	V/ns	1,2,3
Siew late	uv/ut	T <sub>AMB</sub> = T <sub>IND</sub> Scope averaging on	1.6	2.8	4.1	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		7	20	%	1,2,4
Voltage High	VHigh	Statistical measurement on single-ended signal	660	754	850	mV	
Voltage Low	VLow	using oscilloscope math function. (Scope averaging on) -150 62 15		150			
Max Voltage	Vmax	Measurement on single ended signal using		868	1150	mV	
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-64		IIIV	
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	453	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		17	140	mV	1,6

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Measured from differential waveform.

<sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross\_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

<sup>7</sup> At default SMBus settings.

# **Electrical Characteristics–Current Consumption**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
		VDDA, PLL Mode@100MHz		13.4	20	mA	1
Operating Supply Current	I <sub>DDA</sub>	VDDA, PLL Bypass Mode@100MHz		4.8	8	mA	1
	I <sub>DD</sub>	All other VDD pins		16	25	mA	
	I <sub>DDIO</sub>	VDDIO for DIF outputs, if applicable		81	95	mA	
	I <sub>DDA</sub>	VDDA, PLL Mode@100MHz		3	5	mA	1
Davier Davie Current		VDDA, PLL Bypass Mode@100MHz		3	5	mA	1
Power Down Current	I <sub>DD</sub>	All other VDD pins		0.14	1	mA	
	I <sub>DDIO</sub>	VDDIO for DIF outputs, if applicable		0.01	0.3	mA	

<sup>1.</sup> Includes VDDR if applicable

## **Electrical Characteristics–Skew and Differential Jitter Parameters**

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t <sub>SPO_PLL</sub>	Input-to-Output Skew in PLL mode @100MHz, nominal temperature and voltage	-100	3	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t <sub>PD_BYP</sub>	Input-to-Output Skew in Bypass mode @100MHz, nominal temperature and voltage	2.5	3.6	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>DSPO_PLL</sub>	Input-to-Output Skew Variation in PLL mode @100MHz, across voltage and temperature	-50	0	50	ps	1,2,3,5,8
	+	Input-to-Output Skew Variation in Bypass mode @100MHz, across voltage and temperature, T <sub>AMB</sub> = T <sub>COM</sub>	-250		250	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t <sub>dspo_byp</sub>	Input-to-Output Skew Variation in Bypass mode @100MHz, across voltage and temperature, T <sub>AMB</sub> = T <sub>IND</sub>	-350		350	ps	1,2,3,5,8
DIF[x:0]	+	Output-to-Output Skew across all outputs @100MHz, T <sub>AMB</sub> = T <sub>COM</sub>		36	50	ps	1,2,3,8
Dii [X.0]	t <sub>skew_all</sub>	Output-to-Output Skew across all outputs @100MHz, T <sub>AMB</sub> = T <sub>IND</sub>		38	65	ps 1 ps 1 ps dB dB dB MHz MHz	1,2,3,8
PLL Jitter Peaking	j <sub>peak-hibw</sub>	LOBW#_BYPASS_HIBW = 1	0	1.2	2.5	dB	7,8
PLL Jitter Peaking	j <sub>peak-lobw</sub>	LOBW#_BYPASS_HIBW = 0	0	0.8	2	dB	7,8
PLL Bandwidth	рІІ <sub>НІВW</sub>	LOBW#_BYPASS_HIBW = 1	2	3	4	MHz	8,9
PLL Bandwidth	pll <sub>LOBW</sub>	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t <sub>DCD</sub>	Measured differentially, Bypass Mode @100MHz	-1.5	-0.6	0	%	1,10
Jitter, Cycle to cycle	t <sub>jcyc-cyc</sub>	PLL mode		25	50	ps	1,11
, - <u>,</u> <u>,</u> <u>,</u> <u>,</u> <u>,</u> <u>,</u>	JCy C-Cy C	Additive Jitter in Bypass Mode		1	5	ps	1,11

#### Notes for preceding table:

<sup>1</sup> Measured into fixed 2pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

<sup>2</sup> Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

<sup>3</sup> All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

<sup>4</sup> This parameter is deterministic for a given device.

<sup>5</sup> Measured with scope averaging on to find mean value.

<sup>6</sup> t is the period of the input clock.

<sup>7</sup> Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

<sup>8.</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>9</sup> Measured at 3 db down or half power point.

<sup>10</sup> Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

## **Electrical Characteristics–Phase Jitter Parameters**

T<sub>AMB</sub> = T<sub>COM</sub> or T<sub>IND</sub>, unless noted., Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	IND.LIMIT	UNITS	Notes
	t <sub>jphPCIeG1</sub>	PCle Gen 1		36	49	86	ps (p-p)	1,2,3
	t <sub>jphPC1eG2</sub>	PCle Gen 2 Lo Band 10kHz < f < 1.5MHz		1.2	1.6	3	ps (rms)	1,2
Phase Jitter, PLL Mode		PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.2	2.8	3.1	ps (rms)	1,2
	t <sub>jphPCIeG3</sub>	PCle Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.56	0.63	1	ps (rms)	1,2,4
	t <sub>jphQPI_SMI</sub>	QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.22	0.48	0.5	ps (rms)	1,4
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.15	0.28	0.3	ps (rms)	1,4
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.11	0.17	0.2	ps (rms)	1,4
	t <sub>jphPCIeG1</sub>	PCle Gen 1		0.0	0.8	n/a	ps (p-p)	1,2,3
		PCle Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.2	n/a	ps (rms)	1,2,5
	t <sub>jphPC1eG2</sub>	PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.4	0.5	n/a	ps (rms)	1,2,5
<i>Additiv</i> e Phase Jitter, Bypass mode	t <sub>jphPC1eG3</sub>	PCle Gen 3 (PLL BW of 2-4 or 2-5 MHz, CDR = 10MHz)		0.0	0.0	n/a	ps (rms)	1,2,4,5
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.11	0.2	n/a	ps (rms)	1,4,5
	t <sub>jphQPI_SMI</sub>	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.00	0.01	n/a	ps (rms)	1,4,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.00	0.01	n/a	ps (rms)	1,4,5

<sup>1</sup> Applies to all outputs.

<sup>2</sup> See http://www.pcisig.com for complete specs.

<sup>3</sup> Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1<sup>-12</sup>.

<sup>4</sup> Calculated from Intel-supplied Clock Jitter Tool v1.6.3.

<sup>5</sup> For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)<sup>2</sup> - (input jitter)<sup>2</sup>]

# **Clock Periods–Differential Outputs with Spread Spectrum Disabled**

				Ν	Measurement	Window				
	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	F Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

# Clock Periods–Differential Outputs with Spread Spectrum Enabled

				Ν	leasurement	Window				
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC ON	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
DIF	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

Notes:

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

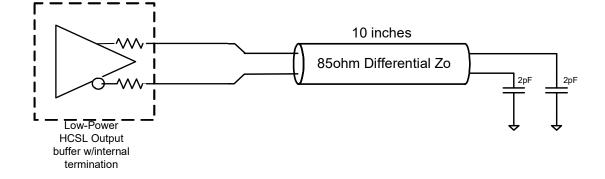
<sup>2</sup> All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZXL1251 itself does not contribute to ppm error.

<sup>3</sup> Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

<sup>4</sup> Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode

#### Differential Output Terminations

DIF Zo (Ω)	Rs (Ω)
100	NA
85	0



# **General SMBus Serial Interface Information for 9ZXL1251**

### How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will **acknowledge**
- Controller (host) sends the byte count = X
- Renesas clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- Renesas clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock \	Write Operation
Controller (	Host)		Renesas (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	ng Byte N		
			ACK
0		×	
0		X Byte	0
0		e	0
			0
Byte N	+ X - 1	]	
			ACK
Р	stoP bit		

### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- Renesas clock will acknowledge
- Renesas clock will send the data byte count = X
- Renesas clock sends Byte N+X-1
- Renesas clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block R	lead C	Operation
Co	ntroller (Host)		Renesas
Т	starT bit		
SI	ave Address		
WR	WRite		
		-	ACK
Begi	nning Byte = N	-	
		-	ACK
RT	Repeat starT	-	
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		

#### SMBusTable: PLL Mode, and Frequency Select Register

Byte	0 Pin #	Name	Control Function	Туре	0	1	Default		
Bit 7	5	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Op	See PLL Operating Mode			
Bit 6	5	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readba	Latch			
Bit 5			Reserved						
Bit 4			Reserved						
Bit 3		PLL_SW_EN	Enable S/W control of PLL BW	RW	HW Latch	SMBus Control	0		
Bit 2		PLL Mode 1	PLL Operating Mode 1	RW	See PLL Op	erating Mode	1		
Bit 1		PLL Mode 0	PLL Operating Mode 1	RW	Readba	1			
Bit 0	4	100M_133M#	Frequency Select Readback	R	133MHz	100MHz	Latch		

**Note:** Setting bit 3 to '1' allows the user to override the Latch value from pin 5 via use of bits 2 and 1. Use the values from the PLL Operating Mode Readback Table. Note that Bits 7 and 6 will keep the value originally latched on pin 5. A warm reset of

#### SMBusTable: Output Control Register

Byte	1 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	47/46	DIF_7_En	Output Control - '0' overrides OE# pin	RW			1
Bit 6	43/42	DIF_6_En	Output Control - '0' overrides OE# pin	RW			1
Bit 5	39/38	DIF_5_En	Output Control - '0' overrides OE# pin	RW			1
Bit 4	35/34	DIF_4_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1
Bit 3	30/31	DIF_3_En	Output Control - '0' overrides OE# pin	RW			1
Bit 2	26/27	DIF_2_En	Output Control - '0' overrides OE# pin	RW			1
Bit 1	21/22	DIF_1_En	Output Control - '0' overrides OE# pin	RW			1
Bit 0	17/18	DIF_0_En	Output Control - '0' overrides OE# pin	RW			1

#### SMBusTable: Output Control Register

Byte	2	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved					0	
Bit 6		Reserved					0	
Bit 5			Reserved				0	
Bit 4			Reserved					0
Bit 3	64	/63	DIF_11_En	Output Control - '0' overrides OE# pin	RW			1
Bit 2	59	9/60	DIF_10_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1
Bit 1	54	/55	DIF_9_En	Output Control - '0' overrides OE# pin	RW			1
Bit 0	50	)/51	DIF_8_En	Output Control - '0' overrides OE# pin	RW			1

#### SMBusTable: Reserved Register

Byte 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6		Reserved					
Bit 5		Reserved					0
Bit 4		Reserved					0
Bit 3		Reserved					0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

#### SMBusTable: Reserved Register

Byte 4	4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6			Reserved					
Bit 5			Reserved				0	
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0

#### SMBusTable: Vendor & Revision ID Register

Byte	5 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	RID3		R	A rev = 0000		Х
Bit 6	-	RID2	REVISION ID	R			Х
Bit 5	-	RID1	REVISIONID	R			Х
Bit 4	-	RID0		R			Х
Bit 3	-	VID3		R			0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1		R	-	-	0
Bit 0	-	VID0		R	-	-	1

#### SMBusTable: DEVICE ID

Byte 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	Device ID 7 (MSB)		R			1
Bit 6	-		Device ID 6	R			1
Bit 5	-		Device ID 5	R			1
Bit 4	-	Device ID 4		R	1251 is 2	51 Decimal	1
Bit 3	-	Device ID 3		R	or F	B Hex	1
Bit 2	-		Device ID 2	R			0
Bit 1	-		Device ID 1	R	]		1
Bit 0	-		Device ID 0	R			1

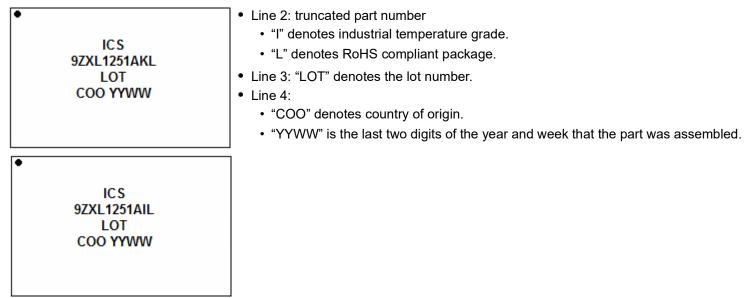
#### SMBusTable: Byte Count Register

Byte	7	Pin #	Name	Control Function	Туре	0	1	Default	
Bit 7				Reserved	Reserved				
Bit 6			Reserved				0		
Bit 5				Reserved			0		
Bit 4		-	BC4		RW			0	
Bit 3		-	BC3	Writing to this register configures how	RW	Default value	1		
Bit 2		-	BC2	many bytes will be read back.	RW	bytes (0 to 8) w	0		
Bit 1		-	BC1	many bytes will be read back.	RW	by de	efault.	0	
Bit 0		-	BC0		RW			0	

#### SMBusTable: Reserved Register

Byte	e 8	Pin #	Name	Control Function	Туре	0	1	Default	
Bit 7				Reserved				0	
Bit 6				Reserved					
Bit 5			Reserved					0	
Bit 4			Reserved					0	
Bit 3			Reserved					0	
Bit 2				Reserved				0	
Bit 1			Reserved						
Bit 0			Reserved						

### **Marking Diagrams**



# Package Outline Drawings

The package outline drawings are appended at the end of this document. The package information is the most current data available.

## **Ordering Information**

Part / Order Number	Shipping Package	Package	Temperature
9ZXL1251AKLF	Trays	64-pin VFQFPN	0 to +70°C
9ZXL1251AKLFT	Tape and Reel	64-pin VFQFPN	0 to +70°C
9ZXL1251AKILF	Trays	64-pin VFQFPN	-40 to +85°C
9ZXL1251AKILFT	Tape and Reel	64-pin VFQFPN	-40 to +85°C

"LF" suffix to the part number denotes Pb-Free configuration, RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

## **Revision History**

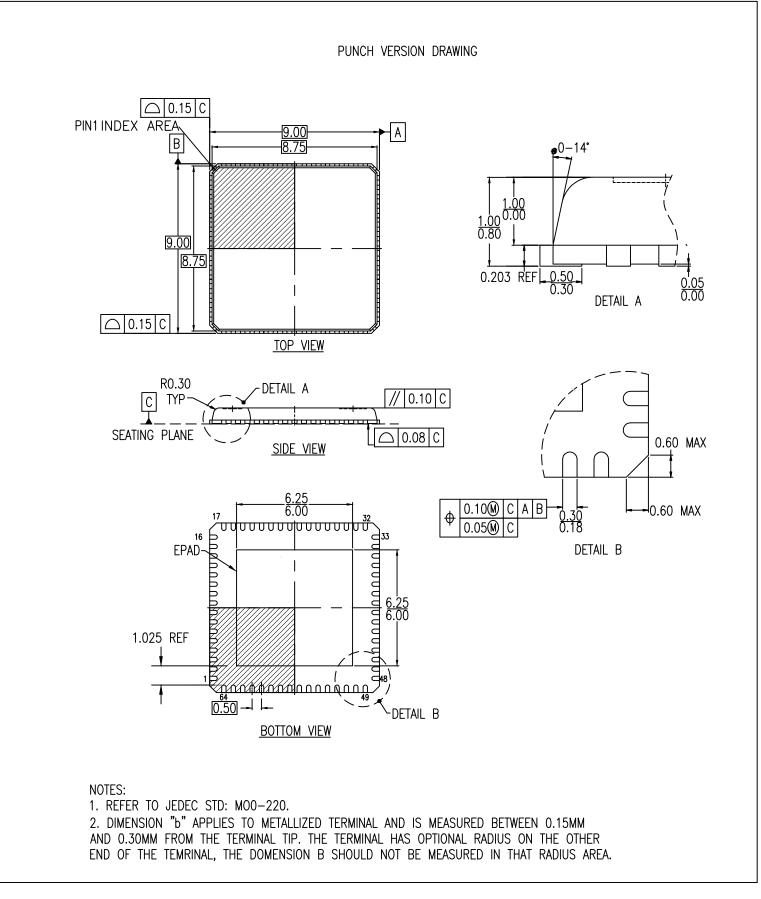
Revision Date	Description
July 23, 2015	Update to final and Release
November 20, 2015	<ol> <li>Updated QPI references to QPI/UPI</li> <li>Updated DIF_IN table to match PCI SIG specification, no silicon change</li> </ol>
January 28, 2021	<ol> <li>Updated input frequency minimum values from 33MHz to 25MHz.</li> <li>Added "25MHz PFT clock delay management" bullet to Features section on cover page.</li> <li>Reformatted headers and footers to Renesas.</li> <li>Updated Marking Diagram and Package Outline Drawings sections.</li> </ol>



### 64-VFQFPN, Package Outline Drawing

9.0 x 9.0 x 0.85 mm Body, 0.5mm Pitch, Epad 6.15 x 6.15 mm

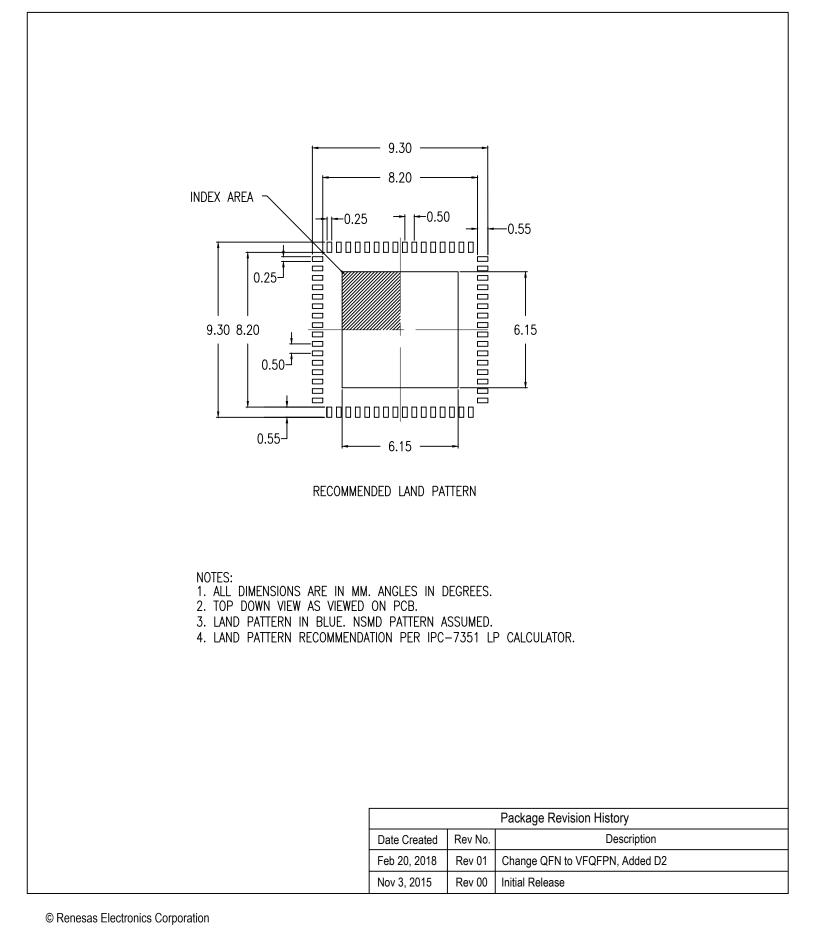
NLG64D2 Punch, PSC-4147-07, Rev 01, Page 1





## 64-VFQFPN, Package Outline Drawing

9.0 x 9.0 x 0.85 mm Body, 0.5mm Pitch, Epad 6.15 x 6.15 mm NLG64D2 Punch, PSC-4147-07, Rev 01, Page 2



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